

### **Description**

The BSS214NW uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

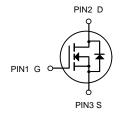


**SOT-323** 

### **General Features**

 $V_{DS} = 20V I_D = 2A$ 

 $R_{DS(ON)} < 55 m\Omega @ V_{GS} = 4.5 V$  $R_{DS(ON)} < 85 m\Omega @ V_{GS} = 2.5 V$ 



# **Application**

Battery protection
Load switch
Uninterruptible power supply

#### N-Channel MOSFET

### **Package Marking and Ordering Information**

| Product ID | Pack    | Brand      | Qty(PCS) |
|------------|---------|------------|----------|
| BSS214NW   | SOT-323 | HXY MOSFET | 3000     |

### Absolute Maximum Ratings (T<sub>A</sub>=25 ℃ unless otherwise noted)

| Symbol                           | Parameter  | Limit      | Unit |
|----------------------------------|--|------------|------|
| V <sub>DS</sub>                  | Drain-Source Voltage                             | 20         | V    |
| V <sub>G</sub> s                 | Gate-Source Voltage                              | ±12        | V    |
| I <sub>D</sub>                   | Drain Current-Continuous                         | 2          | А    |
| Po                               | Maximum Power Dissipation                        | 0.3        | W    |
| T <sub>J</sub> ,T <sub>STG</sub> | Operating Junction and Storage Temperature Range | -55 To 150 | °C   |
| Reja                             | Thermal Resistance,Junction-to-Ambient (Note 2)  | 125        | °C/W |
|                                  |  |            |      |



## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

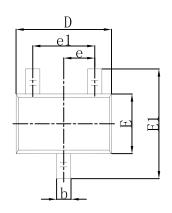
| Parameter   | Symbol               | Test conditions  | Min | Тур | Max  | Unit |  |
|---|----------------------|--|-----|-----|------|------|--|
| STATIC CHARACTERISTICE                                      |                      |  |     |     |      |      |  |
| Drain-source breakdown voltage                              | V <sub>(BR)DSS</sub> | V <sub>GS</sub> = 0V, I <sub>D</sub> =250μA              | 20  |     |      | V    |  |
| Zero gate voltage drain current                             | I <sub>DSS</sub>     | V <sub>DS</sub> =18V,V <sub>GS</sub> = 0V                |     |     | 1    | μΑ   |  |
| Gate-body leakage current                                   | Igss                 | V <sub>GS</sub> =±12V, V <sub>DS</sub> = 0V              |     |     | ±100 | nA   |  |
| Gate threshold voltage (note2)                              | $V_{GS(th)}$         | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA | 0.4 | 0.7 | 1.0  | V    |  |
|   | R <sub>DS(on)</sub>  | V <sub>GS</sub> =4.5V, I <sub>D</sub> =2.0A              |     |     | 55   | mΩ   |  |
| Drain-source on-resistance (note2)                          |                      | V <sub>GS</sub> =2.5V, I <sub>D</sub> =0.3A              |     |     | 85   | mΩ   |  |
| Maximum Continuous Drain to<br>Source Diode Forward Current | Is                   |  |     |     | 1.0  | А    |  |
| Diode forward voltage                                       | V <sub>SD</sub>      | I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V                |     |     | 1.2  | V    |  |
| DYNAMIC CHARACTERISTICS (note3)                             |                      |  |     |     |      |      |  |
| Input capacitance   | C <sub>iss</sub>     |  |     | 300 |      | pF   |  |
| Output capacitance  | Coss                 | V <sub>DS</sub> =10V,V <sub>GS</sub> =0V,<br>f =1MHz     |     | 120 |      | pF   |  |
| Reverse transfer capacitance                                | C <sub>rss</sub>     | 1 - 1101112  |     | 80  |      | pF   |  |
| SWITCHING CHARACTERISTICS (note3)                           |                      |  |     |     |      |      |  |
| Turn-on delay time  | t <sub>d(on)</sub>   |  |     |     | 15   | nS   |  |
| Turn-on rise time   | t <sub>r</sub>       | V <sub>GS</sub> =4.5V,V <sub>DS</sub> =10V,              |     |     | 85   | nS   |  |
| Turn-off delay time   | t <sub>d(off)</sub>  | $R_L$ =5.1 $\Omega$ , $R_G$ =5.1 $\Omega$                |     |     | 65   | nS   |  |
| Turn-off fall time  | t <sub>f</sub>       |  |     |     | 27   | nS   |  |

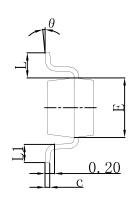
### Notes:

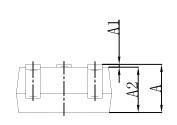
- 1. Surface mounted on FR4 board using the minimum recommended pad size.
- 2. Pulse Test: Pulse Width=300µs, Duty Cycle=2%.
- 3. These parameters have no way to verify.



# **SOT-323 Package Outline Dimensions**







| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |  |
|--------|---------------------------|-------|----------------------|-------|--|
|        | Min                       | Max   | Min                  | Max   |  |
| Α      | 0.900                     | 1.100 | 0.035                | 0.043 |  |
| A1     | 0.000                     | 0.100 | 0.000                | 0.004 |  |
| A2     | 0.900                     | 1.000 | 0.035                | 0.039 |  |
| b      | 0.200                     | 0.400 | 0.008                | 0.016 |  |
| С      | 0.080                     | 0.150 | 0.003                | 0.006 |  |
| D      | 2.000                     | 2.200 | 0.079                | 0.087 |  |
| E      | 1.150                     | 1.350 | 0.045                | 0.053 |  |
| E1     | 2.150                     | 2.450 | 0.085                | 0.096 |  |
| е      | 0.650                     | TYP   | 0.026 TYP            |       |  |
| e1     | 1.200                     | 1.400 | 0.047                | 0.055 |  |
| L      | 0.525 REF                 |       | 0.021 REF            |       |  |
| L1     | 0.260                     | 0.460 | 0.010                | 0.018 |  |
| K      | 0°                        | 8°    | 0°                   | 8°    |  |



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